# UNISONIC TECHNOLOGIES CO., LTD

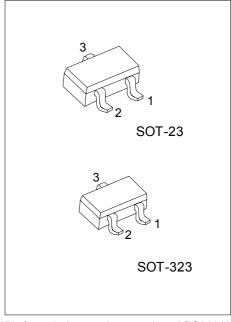
2SC3838

#### **NPN SILICON TRANSISTOR**

## **HIGH-FREQUENCY AMPLIFIER TRANSISTOR**

#### **■ FEATURES**

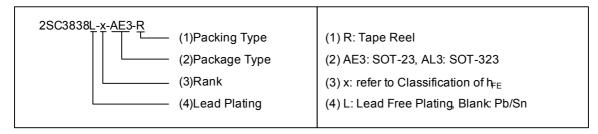
- \*High transition frequency.
- \*Small rbb'·Cc and high gain.
- \*Small NF.



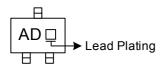
\*Pb-free plating product number: 2SC3838L

#### **■ ORDERING INFORMATION**

Order I	Package	Pin Assignment			Dooking	
Normal	Normal Lead Free Plating		1	2	3	Packing
2SC3838-x-AE3-R	2SC3838L-x-AE3-R	SOT-23	Е	В	С	Tape Reel
2SC3838-x-AL3-R	2SC3838L-x-AL3-R	SOT-323	Е	В	С	Tape Reel



#### **MARKING**



www.unisonic.com.tw 1 of 2 QW-R220-018,B

#### ■ ABSOLUTE MAXIMUM RATINGS (Ta = 25 )

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	$V_{CBO}$	20	٧
Collector-Emitter Voltage	$V_{CEO}$	11	٧
Emitter-Base Voltage	$V_{EBO}$	3	٧
Collector current	I <sub>C</sub>	50	mA
Collector power dissipation	$P_{D}$	0.2	W
Junction Temperature	$T_J$	+150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~ <b>+</b> 150	°C

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ **ELECTRICAL CHARACTERISTICS** (Ta= 25 , unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> =10μA				V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> =1mA				V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> =10μA	3			V
Collector cutoff current	I <sub>CBO</sub>	V <sub>CB</sub> =10V			0.5	μΑ
Emitter cutoff current	I <sub>EBO</sub>	V <sub>EB</sub> =2V			0.5	μΑ
Collector-emitter saturation voltage	V <sub>CE(SAT)</sub>	$I_C$ =10mA, $I_B$ = 5mA			0.5	V
DC current transfer ratio	h <sub>FE</sub>	$V_{CE}$ =10V, $I_{C}$ =5mA	56		400	
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>E</sub> =10mA, f=500MHz	1.4	3.2		GHz
Output capacitance	Cob	V <sub>CB</sub> =10V, I <sub>E</sub> =0A, f=1MHz		0.8	1.5	pF
Collector-base time constant	rbb'·Cc	V <sub>CB</sub> =10V, I <sub>C</sub> =10mA, f=31.8MHz		4	12	ps
Noise factor	NF	$V_{CE}$ =6V, $I_{C}$ =2mA, f=500MHz, Rg=50 $\Omega$		3.5		dB

### ■ CLASSIFICATION of h<sub>FE</sub>

RANK	Α	В	С	D	
RANGE	56 ~ 110	100 ~ 170	120 ~ 270	250 ~ 400	

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